## NSN 5962-01-096-4917

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View Online at https://aerobasegroup.com/nsn/5962-01-096-4917 **Body Length:** 0.870 inches **Body Width:** Between 0.280 inches and 0.300 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 750.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and w/enable and programmable and programmed and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Product Name:** Programmed rom bite & synchronizer Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source and -1.0 volts input and 5.5 volts input **Memory Device Type:** Prom **Memory Capacity:** 256 words x 4 bits **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Test Data Document:** 97942-581r679 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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